1. General description

NPN/NPN matched double transistors in a small SOT457 (SC-74) Surface-Mounted Device (SMD) plastic package.

PNP/PNP complement: BCM53DS

2. Features and benefits

- High collector current capability I_C and I_{CM}
- Reduces component count
- Reduces pick and place costs
- Current gain matching 5%
- · Application-optimized pinout
- AEC-Q101 qualified

3. Applications

- Current mirror
- Differential amplifier
- · Linear voltage regulators
- MOSFET drivers
- High-side switches
- Power management
- Amplifiers

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Per transistor	Per transistor							
V _{CEO}	collector-emitter voltage	open base		-	-	80	V	
I _C	collector current			-	-	1	Α	
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-	2	Α	
h _{FE}	DC current gain	V_{CE} = 2 V; I_{C} = 150 mA; T_{amb} = 25 °C	[1]	63	-	250		
Per device								
h _{FE1} /h _{FE2}	DC current gain matching	$V_{CE} = 5 \text{ V}; I_{C} = 2 \text{ mA}; T_{amb} = 25 \text{ °C}$		0.95	1	1.05		



80 V, 1 A NPN/NPN matched double transistors

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{BE1} -V _{BE2}	base-emitter voltage matching		[2]	-	-	2	mV

- [1] Pulse test: $t_0 \le 300 \,\mu\text{s}$; $\delta \le 0.02$
- [2] The smaller of the two values is subtracted from the larger value.

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol	
1	B1	base TR1	<u> </u>	C1 E1 E2	
2	B2	base TR2		TR1 TR2	
3	C2	collector TR2	TSOP6 (SOT457)		
4	E2	emitter TR2			
5	E1	emitter TR1			aaa-024629
6	C1	collector TR1			

6. Ordering information

Table 3. Ordering information

Type number	Package	kage				
	Name	Description	Version			
BCM56DS	TSOP6	plastic, surface-mounted package (SC-74)	SOT457			

7. Marking

Table 4. Marking codes

Type number	Marking code
BCM56DS	3D

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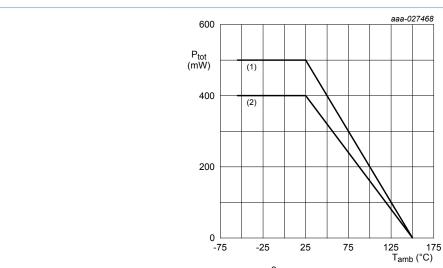
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transist	or		,			
V _{CBO}	collector-base voltage	open emitter		-	100	V
V _{CEO}	collector-emitter voltage	open base		-	80	V
V _{EBO}	emitter-base voltage	open collector		-	5	V
I _C	collector current			-	1	Α
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	2	Α
I _{Blim}	limiting base current			-	0.2	Α
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms		-	0.3	Α
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	270	mW
			[2]	-	320	mW
Per device						
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	400	mW
			[2]	-	500	mW
T _j	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

- Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint. Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated; mounting pad for collector 1 cm².



- (1) = FR4 PCB, single sided copper, 1 cm^2
- (2) = FR4 PCB, single sided copper, standard footprint

Per device: Power derating curves Fig. 1.

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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	tor					,	
R _{th(j-a)}	thermal resistance	in free air	[1]	-	-	463	K/W
from juncti ambient	from junction to ambient		[2]	-	-	391	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	150	K/W
Per device							
$R_{\text{th(j-a)}}$	thermal resistance	in free air	[1]	-	-	313	K/W
	from junction to ambient		[2]	-	-	250	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated; mounting pad for collector 1 cm².

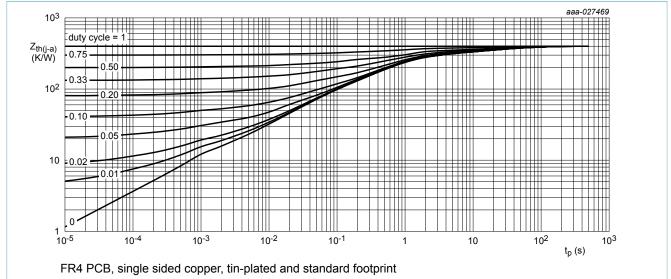
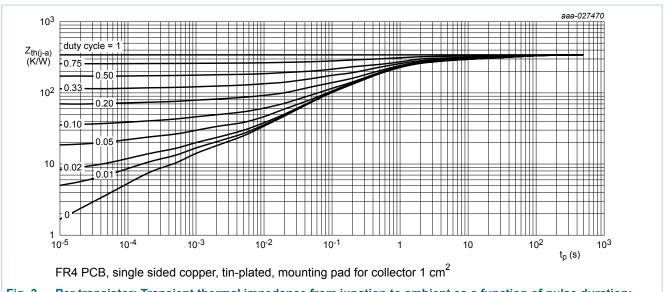


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transisto	or						
V _{(BR)CBO}	collector-base breakdown voltage	I _C = 100 μA; I _E = 0 A		100	-	-	V
V _{(BR)CEO}	collector-emitter breakdown voltage	I _C = 2 mA; I _B = 0 A		80	-	-	V
$V_{(BR)EBO}$	emitter-base breakdown voltage	$I_C = 0 \text{ A}; I_E = 100 \mu\text{A}$		5	-	-	V
I _{CBO}	collector-base cut-off	V _{CB} = 30 V; I _E = 0 A; T _{amb} = 25 °C		-	-	100	nA
	current	V _{CB} = 30 V; I _E = 0 A; T _j = 150 °C		-	-	10	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	100	nA
h _{FE}	DC current gain	V _{CE} = 5 V; I _C = 2 mA; T _{amb} = 25 °C		63	-	-	
		V _{CE} = 2 V; I _C = 150 mA; T _{amb} = 25 °C	[1]	63	-	250	
		V_{CE} = 2 V; I_{C} = 500 mA; T_{amb} = 25 °C	[1]	40	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_{\rm C}$ = 500 mA; $I_{\rm B}$ = 50 mA; $T_{\rm amb}$ = 25 °C	[1]	-	-	500	mV
V_{BE}	base-emitter voltage	V_{CE} = 2 V; I_{C} = 500 mA; T_{amb} = 25 °C	[1]	-	-	1	V
C _c	collector capacitance	V _{CB} = 10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C		-	4.5	-	pF
f _T	transition frequency	V_{CE} = 5 V; I_{C} = 50 mA; f = 100 MHz; T_{amb} = 25 °C		100	155	-	MHz
Per device							
h _{FE1} /h _{FE2}	DC current gain matching	$V_{CE} = 5 \text{ V}; I_{C} = 2 \text{ mA}; T_{amb} = 25 \text{ °C}$		0.95	1	1.05	
V _{BE1} -V _{BE2}	base-emitter voltage matching		[2]	-	-	2	mV

Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02$ The smaller of the two values is subtracted from the larger value.

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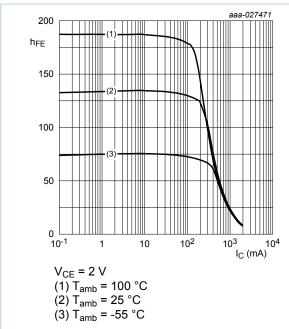


Fig. 4. DC current gain as a function of collector current; typical values

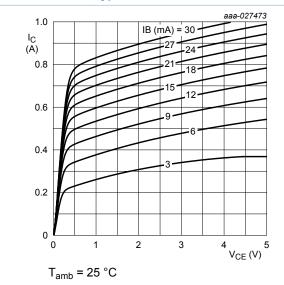


Fig. 6. Collector current as a function of collectoremitter voltage; typical values

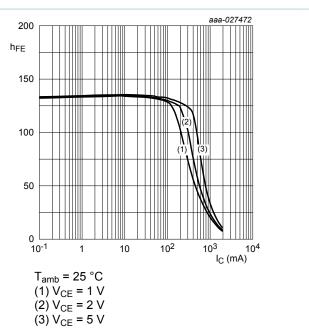


Fig. 5. DC current gain as a function of collector current; typical values

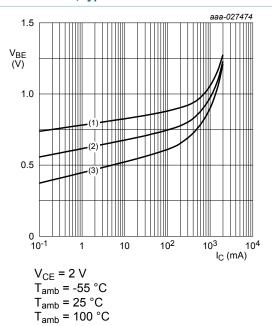


Fig. 7. Base-emitter voltage as a function of collector current; typical values

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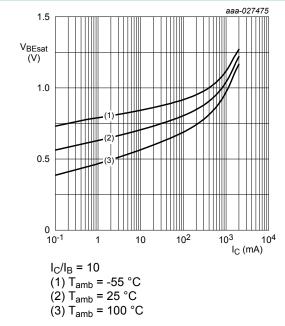


Fig. 8. Base-emitter saturation voltage as a function of collector current; typical values

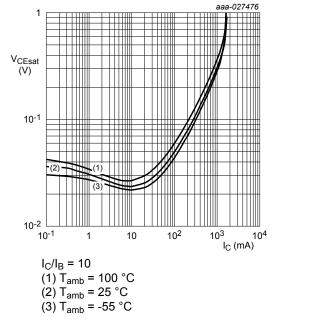


Fig. 9. Collector-emitter saturation voltage as a function of collector current; typical values

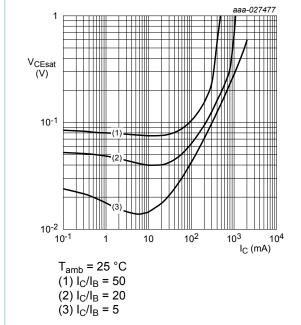


Fig. 10. Collector-emitter saturation voltage as a function of collector current; typical values

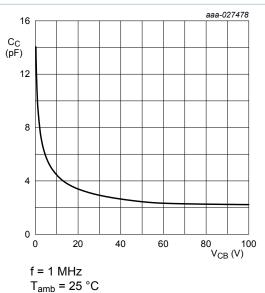


Fig. 11. Collector capacitance as a function of collector-base voltage; typical values

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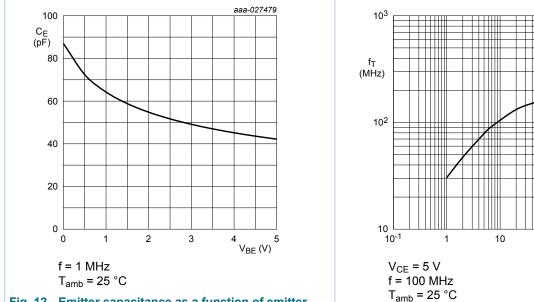


Fig. 12. Emitter capacitance as a function of emitterbase voltage; typical values

Fig. 13. Transition frequency as a function of collector current; typical values

10²

10³

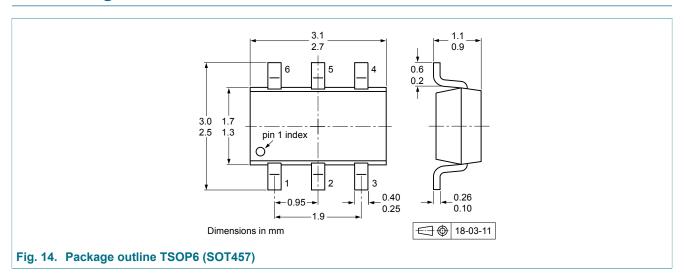
I_C (mA)

11. Test information

Quality information

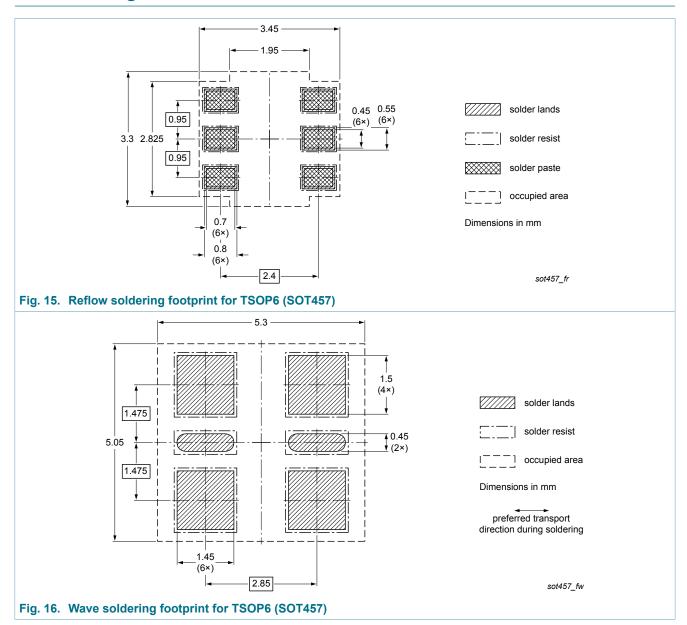
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



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13. Soldering



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14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BCM56DS v.1	20180410	Product data sheet	-	-

80 V, 1 A NPN/NPN matched double transistors

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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